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Journal Name:	Physical Science International Journal	
Manuscript Number:	Ms_PSIJ_29024	
Title of the Manuscript:	Influence of Annealing Temperature on the Physical Properties of Polycrystalline Cu2SnSe3 Thin Films Prepared by Thermal Vacuum Evaporation Technique	
Type of the Article	Original Research Article	

General guideline for Peer Review process:

This journal's peer review policy states that <u>NO</u> manuscript should be rejected only on the basis of '<u>lack of Novelty'</u>, provided the manuscript is scientifically robust and technically sound.

To know the complete guideline for Peer Review process, reviewers are requested to visit this link:

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PART 1: Review Comments

	Reviewer's comment	Author's comment (if agreed with reviewer, correct the manuscript and highlight that part in the manuscript. It is mandatory that authors
Compulsory REVISION	The paper shows results of thermally evaporated Cu2SnSe3.	
comments	After different temperature annealing a series of physical	
commonito	properties have been investigated. However, the paper needs	
	a lot of improvements before it can be considered for the	
	journal.	
	 Cu2SnSe3 is a popular material for photovoltaic application, which has been clearly stated in the introduction part by authors. However, there is no conclusive result about the band gap of the material. Authors show activation energy of 0.018 eV, using the annealing temperature as the reference. Authors should read more papers about activation energy calculation and photovoltaic effect. No crystal structures results. Authors should at least give some XRD to confirm the Cu2SnSe3 phase. Thermally evaporated Cu2SnSe3 has been extensively studied. Authors should consider more deep analysis of the system. 	
Minor REVISION	•	
comments		
Optional/General		
comments		

Reviewer Details:

Name:	Anonymous
Department, University & Country	Virginia Tech, Blacksburg, VA , USA